

25.0 A Single-Phase Silicon Bridge Rectifier



Rectifier Reverse Voltage 50 to 1000V

Features

- Ideal for P.C. Board mounting
- High surge current capability
- This series is UL listed under the Recognized Component Index, file number E142814
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- High temperature soldering guaranteed 265°C /10 seconds at 5 lbs (2.3kg) tension

Mechanical Data

Case: Molded plastic body

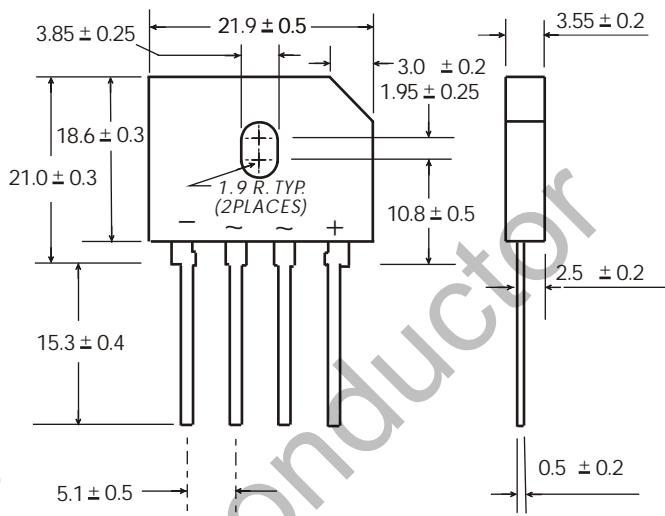
Terminals: Plated leads solderable per MIL-STD-202,
Method 208

Polarity: Polarity symbols molded on body

Mounting Position:: Any

Mounting Torque: 5 in-lbs max.

Weight: 3.8 grams (approx)



Dimensions in millimeters(1mm = 0.0394")

Maximum Ratings & Thermal CharacteristicsRating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz.
For Capacitive load derate current by 20%.

Parameter	Symbol	GBU 2500	GBU 2501	GBU 2502	GBU 2504	GBU 2506	GBU 2508	GBU 2510	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current at TA=100°C	IF(AV)				25				A
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM				350				A
Rating for fusing (t<8.3ms)	I ² t				200				A ² sec
Typical thermal resistance per element (1)	ReJA				2.2				°C / W
Operating junction and storage temperature range	TJ, TSTG				-55 to + 150				°C

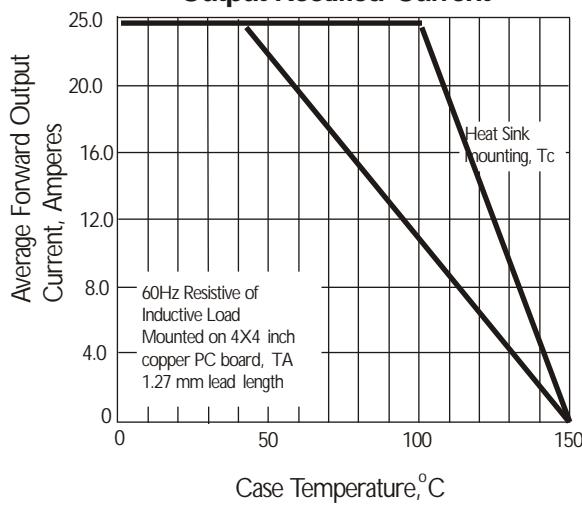
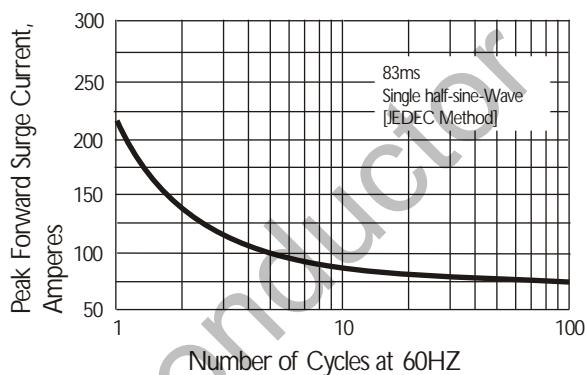
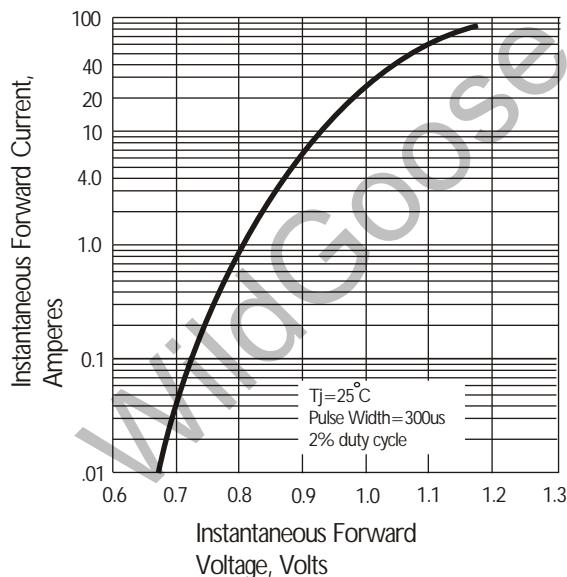
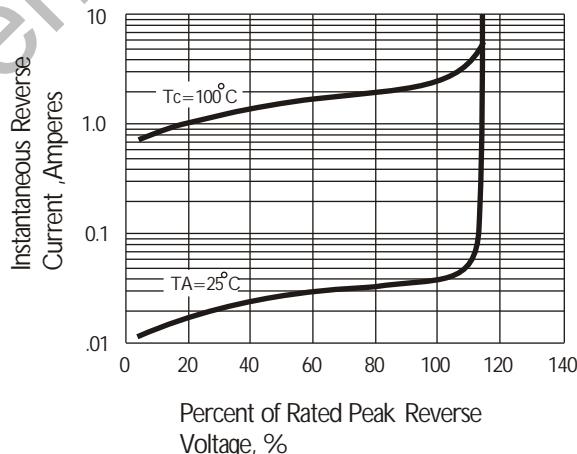
Electrical CharacteristicsRating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz.
For Capacitive load derate by 20 %.

Parameter	Symbol	GBU 2500	GBU 2501	GBU 2502	GBU 2504	GBU 2506	GBU 2508	GBU 2510	Unit
Maximum instantaneous forward voltage drop per leg at 10.0A	VF				1.05				V
Maximum DC reverse current at rated TA =25°C DC blocking voltage per element TA =125°C	IR				5.0 500				μA

Notes: (1)Thermal resistance from Junction to Ambient on P.C.board mounting.

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Rating and Characteristic Curves ($T_A = 25^\circ\text{C}$ Unless otherwise noted)
GBU2500 thru GBU2510**Fig. 1 Derating Curve for Output Rectified Current****Fig. 2 Maximum Non-repetitive Peak Forward Surge Current****Fig. 3 Typical Instantaneous Forward Characteristics****Fig. 4 Typical Reverse Characteristics****Fig. 5 Typical Junction Capacitance**